

## **NCE N-Channel Super Trench Power MOSFET**

### **Description**

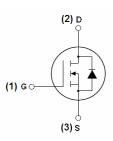
The NCEP01T25T uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS(ON)}}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

- $V_{DS}$  =100V, $I_{D}$  =250A  $R_{DS(ON)}$  <2.5mΩ @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



Schematic diagram



TO-247 top view

100% UIS TESTED!

100% AVds TESTED!

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP01T25T	NCEP01T25T	TO-247	-	-	-

### Absolute Maximum Ratings (T<sub>c</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	100	V	
Gate-Source Voltage	V <sub>GS</sub>	±20	V	
Drain Current-Continuous	I <sub>D</sub>	250	А	
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	175	А	
Pulsed Drain Current	I <sub>DM</sub>	1000	А	
Maximum Power Dissipation	P <sub>D</sub>	400	W	
Derating factor		2.67	W/℃	
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	2000	mJ	
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}\mathbb{C}$	

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>0</sub> JC	0.38	°C/W
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## Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	3	-	5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =125A	-	2.2	2.5	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =125A	-	120	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>lss</sub>	\/ -50\/\/ -0\/	-	15700	-	PF
Output Capacitance	Coss	$V_{DS}$ =50V, $V_{GS}$ =0V, F=1.0MHz	_	1600	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVITIZ	-	101	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	30	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =50 $V$ , $I_{D}$ =125 $A$	-	85	-	nS
Turn-Off Delay Time	$t_{d(off)}$	$V_{GS}$ =10 $V$ , $R_{G}$ =1.8 $\Omega$	-	95	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	38	-	nS
Total Gate Charge	Qg	V -50VI -405A	-	208		nC
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =50V,I <sub>D</sub> =125A,	-	86		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	38.4		nC
Drain-Source Diode Characteristics	•		•			•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>F</sub> = 125A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	250	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = I_S$	-	115		nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	320		nC

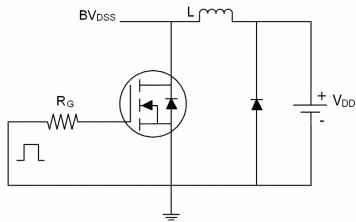
### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$

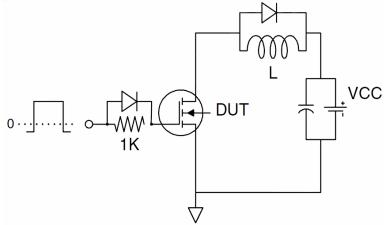


### **Test Circuit**

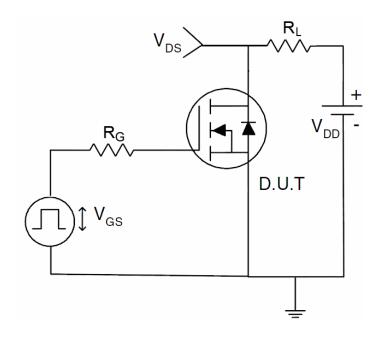
## 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit

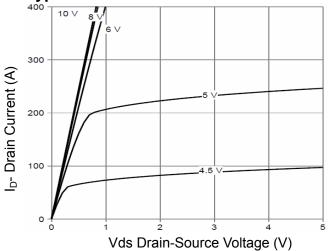


## 3) Switch Time Test Circuit

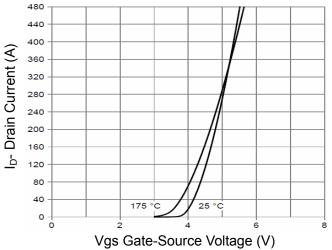








**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

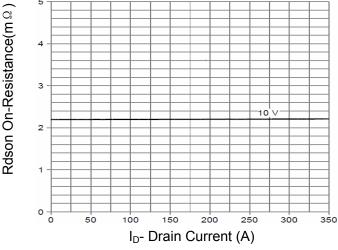


Figure 3 Rdson- Drain Current

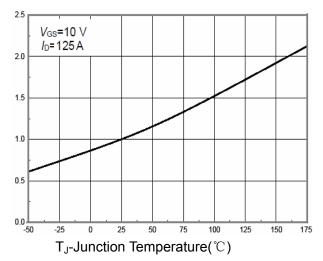


Figure 4 Rdson-JunctionTemperature

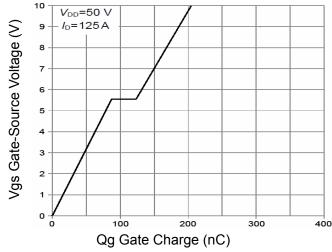


Figure 5 Gate Charge

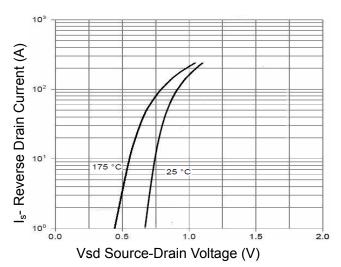
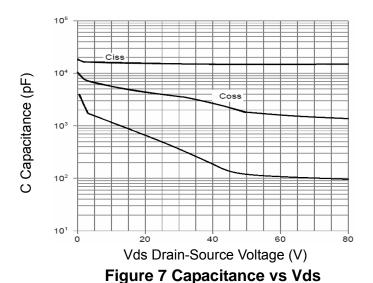
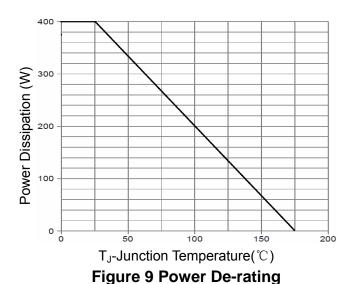


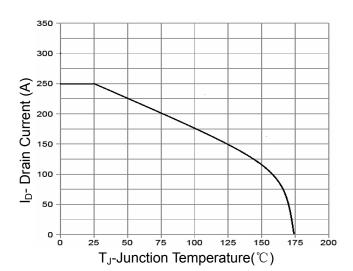
Figure 6 Source- Drain Diode Forward





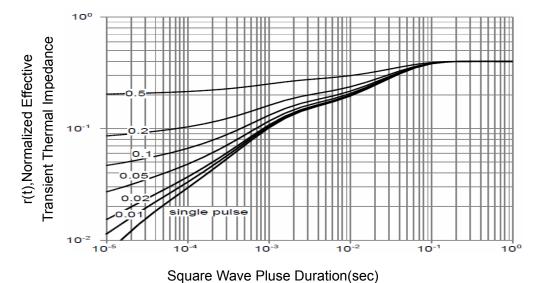


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**Figure 8 Safe Operation Area** 

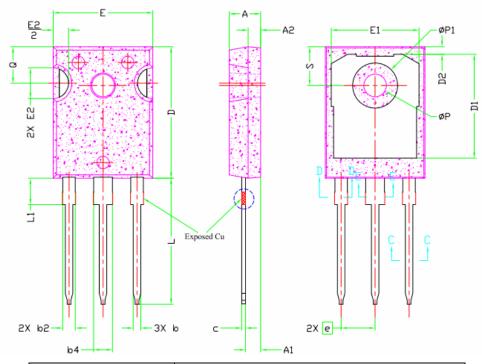
Figure 10 Current De-rating



**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **TO-247 Package Information**



Symbol	Dimensions In Millimeters				
Symbol	Min.	Nom.	Max.		
A	4.83	5.02	5.21		
A1	2.29	2.41	2.55		
A2	1.50	2.00	2.49		
b	1.12	1.20	1.33		
b1	1.12	1.20	1.28		
b2	1.91	2.00	2.39		
b3	1.91	2.00	2.34		
b4	2.87	3.00	3.22		
b5	2.87	3.00	3.18		
С	0.55	0.60	0.69		
c1	0.55	0.60	0.65		
D	20.80	20.95	21.1		
D1	16.25	16.55	17.65		
D2	0.51	1.19	1.35		
E	15.75	15.94	16.13		
E1	13.46	14.02	14.16		
E2	4.32	4.91	5.49		
L	19.81	20.07	20.32		
L1	4.10	4.19	4.40		
Q	5.39	5.79	6.20		
ФР	3.56	3.61	3.65		
S	6.04	6.17	6.30		



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